SCBS014B - NOVEMBER 1988 - REVISED NOVEMBER 1993

- BiCMOS Design Substantially Reduces Standby Current
- Functionally Equivalent to 'ALS29862 and AMD Am29862A
- Power-Up High-Impedance State
- ESD Protection Exceeds 2000 V Per Mil-STD-883C, Method 3015
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (JT, NT)

description

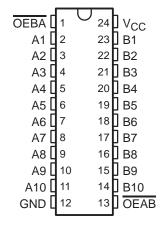
These 10-bit bus transceivers are designed for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the output-enable (OEBA and OEAB) inputs.

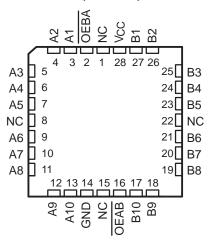
The outputs are in the high-impedance state during power-up and power-down conditions. The outputs remain in the high-impedance state while the device is powered-down.

The SN54BCT29862B is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT29862B is characterized for operation from 0°C to 70°C.

SN54BCT29862B . . . JT OR W PACKAGE SN74BCT29862B . . . DW OR NT PACKAGE (TOP VIEW)



SN54BCT29862B . . . FK PACKAGE (TOP VIEW)

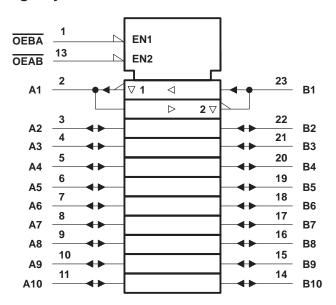


NC - No internal connection

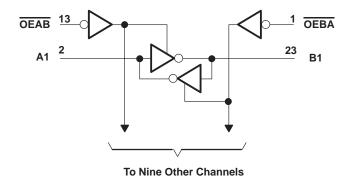
FUNCTION TABLE

INP	UTS	OPERATION					
OEAB	OEBA	OI EKATION					
L	Н	A to B					
Н	L	B to A					
Н	Н	Isolation					
L	L	Latch A and B $(A = \overline{B})$					

logic symbol†



logic diagram (positive logic)



Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V _{CC}		0.5 V to 7 V
Input voltage (I/O ports) (see Note 1) .		
Input voltage (excluding I/O ports) (see	Note 1)	$-0.5\ V$ to 7 V
Voltage applied to any output in the high	n state	-0.5 V to V_{CC}
Input clamp current		30 mA
Current into any output in the low state:	SN54BCT29862B	48 mA
	SN74BCT29862B	96 mA
Operating free-air temperature range:	SN54BCT29862B	–55°C to 125°C
	SN74BCT29862B	0°C to 70°C
Storage temperature range		65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input negative voltage rating may be exceeded if the input clamp current rating is observed.

recommended operating conditions

		SN54BCT29862B			SN74BCT29862B			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
lik	Input clamp current			-18			-18	mA
ЮН	High-level output current			-12			-24	mA
loL	Low-level output current			24			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54BCT29862B			SN74BCT29862B			LINUT	
				MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT	
VIK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
V		V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2.4	3.3		2.4	3.3		V	
VOH		VCC = 4.5 V	$I_{OH} = -24 \text{ mA}$				2	3.1		V	
Va.		V _{CC} = 4.5 V	I _{OL} = 24 mA		0.35	0.5				V	
VOL		VCC = 4.5 V	I _{OL} = 48 mA					0.35	0.5	v	
Ц		$V_{CC} = 5.5 \text{ V},$	V _I = 5.5 V			0.1			0.1	mA	
1	Control inputs	Va. 5.5.V	V _I = 2.7 V			20			20	μΑ	
ΉΗ	A or B port‡	V _{CC} = 5.5 V,				70			70		
1	Control inputs	V-0 F-5 V	/ 55V V 05V			-0.2			-0.2	mA	
¹ı∟	A or B port [‡]	V _{CC} = 5.5 V,	V _I = 0.5 V		-0.2				-0.2	IIIA	
I _{IO(off)} §		$V_{CC} = 0$,	V _O = 2.7 V			0.1			0.1	mA	
los¶		V _{CC} = 5.5 V,	VO = 0	-75		-250	-75		-250	mA	
			Outputs high		20	32		20	32		
Icc		$V_{CC} = 5.5 V$	Outputs low		29	46		29	46	mA	
			Outputs disabled		6.5	11		6.5	11		
Ci		V _{CC} = 5 V,	V _I = 0.5 V or 2.5 V		6			6		pF	
Co		V _{CC} = 5 V,	V _I = 0.5 V or 2.5 V		8			8		pF	

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5 \text{ V},$ $C_L = 50 \text{ pF},$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_A = 25^{\circ}C$			V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω , R2 = 500 Ω , T_A = MIN to MAX#				UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
tPLH	A or B	A or B B or A	1	3.6	5.2	1	6.5	1	6.1	
t _{PHL}			0.5	2.4	4.6	0.5	7.5	0.5	4.8	ns
^t PZH	ŌĒ	A or B	2.5	5.3	7.2	2.5	9.1	2.5	8.4	ns
t _{PZL}		OE AOIB	4.5	8	10.6	4.5	13.9	4.5	12.5	115
^t PHZ	ŌĒ	A or B	2.3	4.8	7.6	2.3	8.4	2.3	8.4	ns
tPLZ		AUB	2.3	5.2	7	2.3	9.1	2.3	8.2	115

[#] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ I_{O(off)} = Power-off bus leakage current
¶ Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

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